MSD42WT1G, NSVMSD42WT1G

NPN High Voltage Transistors

This NPN Silicon Planar Transistor is designed for general purpose amplifier applications. This device is housed in the SC-70/SOT-323 package which is designed for low power surface mount applications.

Features

- These Devices are Pb-Free, Halogen Free and are RoHS Compliant
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable

MAXIMUM RATINGS ($T_A = 25^{\circ}C$)

Rating	Symbol	Value	Unit
Collector-Base Voltage	V _{(BR)CBO}	300	V
Collector-Emitter Voltage	V _{(BR)CEO}	300	V
Emitter-Base Voltage	V _{(BR)EBO}	6.0	V
Collector Current – Continuous	Ι _C	150	mA

THERMAL CHARACTERISTICS

Rating	Symbol	Max	Unit
Power Dissipation (Note 1)	P _D	450	mW
Thermal Resistance, Junction-to-Ambient (Note 1)	R_{\thetaJA}	274	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	–55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Min	Max	Unit
Collector-Emitter Breakdown Voltage (I _C = 1.0 mA, I _B = 0)	V _{(BR)CEO}	300	-	V
Collector-Base Breakdown Voltage $(I_C = 100 \ \mu A, I_E = 0)$	V _{(BR)CBO}	300	-	V
Emitter-Base Breakdown Voltage (I _E = 100 μ A, I _E = 0)	V _{(BR)EBO}	6.0	-	V
Collector-Base Cutoff Current $(V_{CB} = 200 \text{ V}, I_E = 0)$	I _{CBO}	-	0.1	μA
Emitter-Base Cutoff Current $(V_{EB} = 6.0 \text{ V}, I_B = 0)$	I _{EBO}	-	0.1	μA
DC Current Gain (Note 2) ($V_{CE} = 10 \text{ V}, I_C = 1.0 \text{ mA}$) ($V_{CE} = 10 \text{ V}, I_C = 30 \text{ mA}$)	h _{FE1} h _{FE2}	25 40	-	-
Collector-Emitter Saturation Voltage (Note 2) (I _C = 20 mA, I _B = 2.0 mA)	V _{CE(sat)}	-	0.5	V

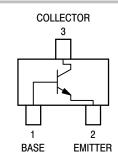
1. FR-4 @ 10 mm², 1 oz. Copper traces.

2. Pulse Test: Pulse Width \leq 300 μ s, D.C. \leq 2%.



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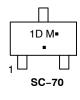
http://onsemi.com





SC-70 (SOT-323) CASE 419 STYLE 3

MARKING DIAGRAM



1D = Specific Device Code Μ

= Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

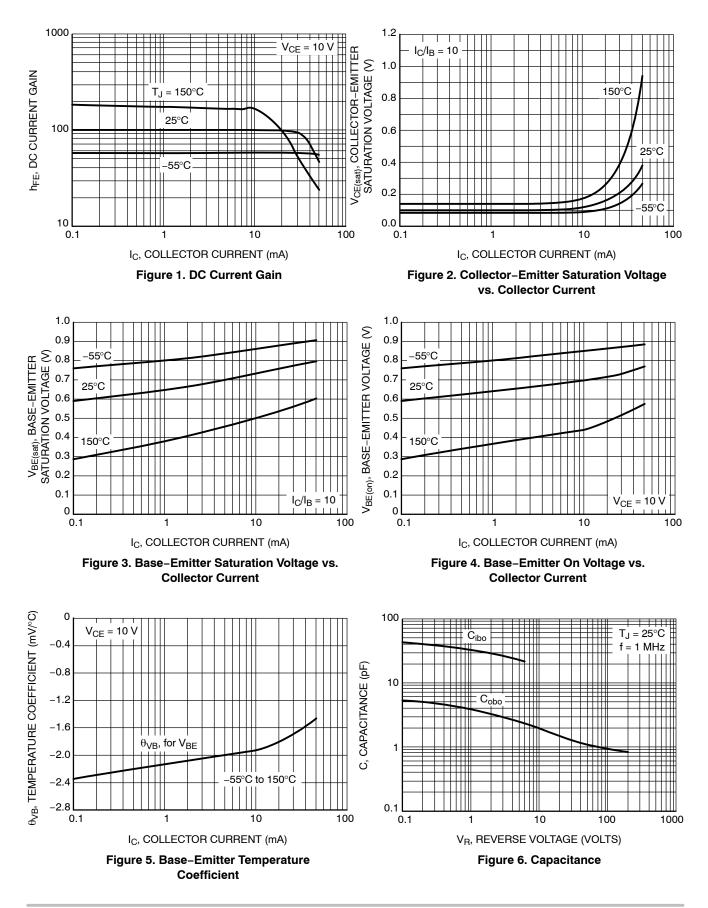
ORDERING INFORMATION

Device	Package	Shipping [†]
MSD42WT1G	SC-70 (Pb-Free)	3000 / Tape & Reel
NSVMSD42WT1G	SC-70 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

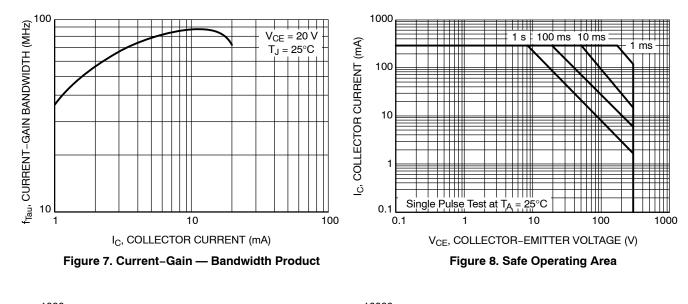
MSD42WT1G, NSVMSD42WT1G

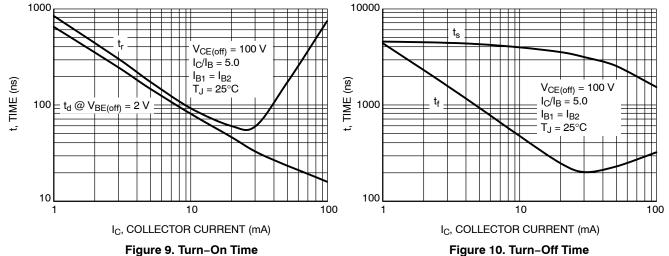
TYPICAL CHARACTERISTICS



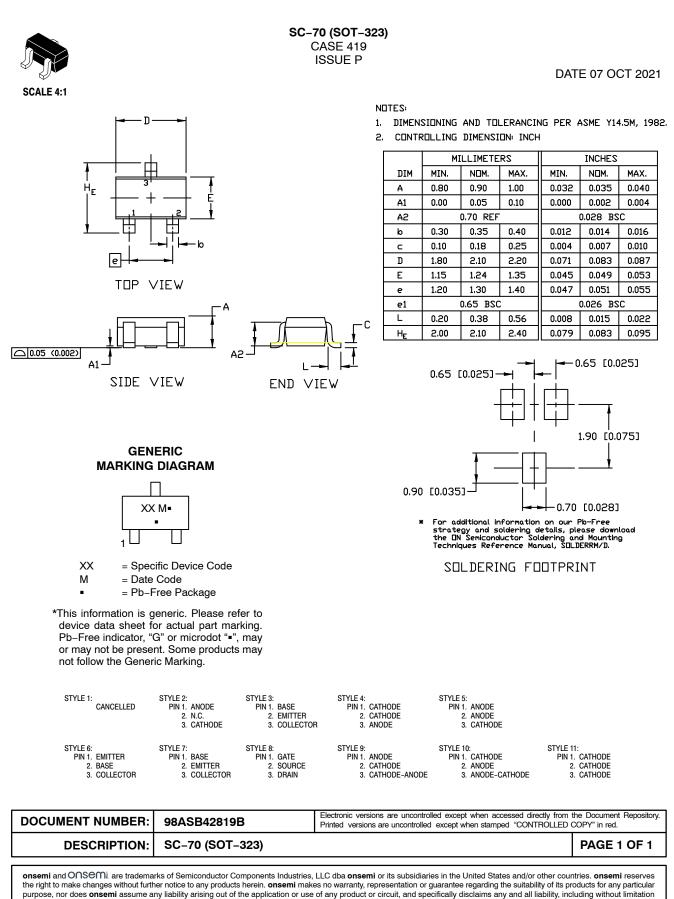
MSD42WT1G, NSVMSD42WT1G

TYPICAL CHARACTERISTICS





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